

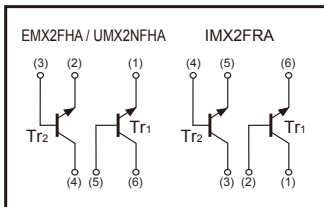
General purpose (dual transistors)

EMX2FHA / UMX2NFHA / IMX2FRA

●Features

- 1) Two 2SC2412AK chips in a EMT or UMT or SMT package.

●Equivalent circuits



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CBO}	60	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EB0}	7	V
Collector current	I _c	150	mA
Collector power dissipation	P _C	150(TOTAL)	mW *1
		300(TOTAL)	
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

*1 120mW per element must not be exceeded.
*2 200mW per element must not be exceeded.

●Package, marking, and packaging specifications

Type	EMX2FHA	UMX2NFHA	IMX2FRA
Package	EMT6	UMT6	SMT6
Marking	X2	X2	X2
Code	T2R	TR	T108
Basic ordering unit (pieces)	8000	3000	3000

●External dimensions (Unit : mm)

EMX2FHA

ROHM : EMT6 Each lead has same dimensions

UMX2NFHA

ROHM : UMT6 Each lead has same dimensions
EIAJ : SC-88

IMX2FRA

ROHM : SMT6 Each lead has same dimensions
EIAJ : SC-74

Transistors

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CBO}	60	–	–	V	I _C =50μA
Collector-emitter breakdown voltage	BV _{CEO}	50	–	–	V	I _C =1mA
Emitter-base breakdown voltage	BV _{EBO}	7	–	–	V	I _E =50μA
Collector cutoff current	I _{CBO}	–	–	0.1	μA	V _{CB} =60V
Emitter cutoff current	I _{EBO}	–	–	0.1	μA	V _{EB} =7V
Collector-emitter saturation voltage	V _{CE(sat)}	–	–	0.4	V	I _C /I _B =50mA/5mA
DC current transfer ratio	h _{FE}	120	–	560	–	V _{CE} =6V, I _C =1mA
Transition frequency	f _T	–	180	–	MHz	V _{CE} =12V, I _E =–2mA, f=100MHz *
Output capacitance	C _{ob}	–	2	3.5	pF	V _{CB} =12V, I _E =0mA, f=1MHz

*Transition frequency of the device.

●Electrical characteristics curves

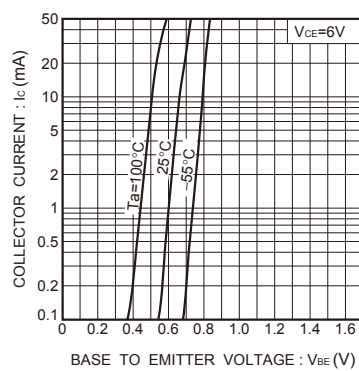


Fig.1 Grounded emitter propagation characteristics

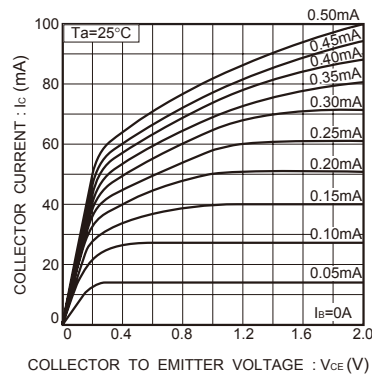


Fig.2 Grounded emitter output characteristics (I)

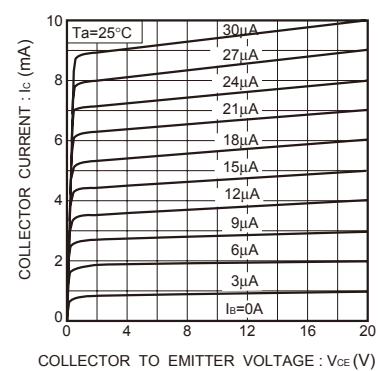


Fig.3 Grounded emitter output characteristics (II)

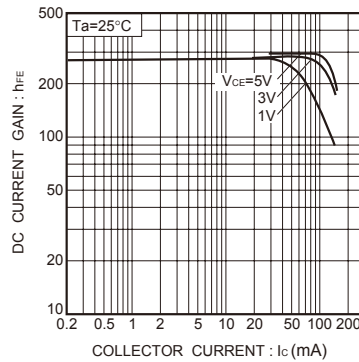


Fig.4 DC current gain vs. collector current (I)

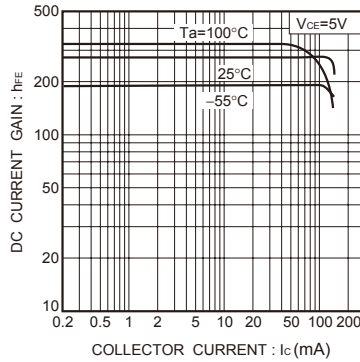


Fig.5 DC current gain vs. collector current (II)

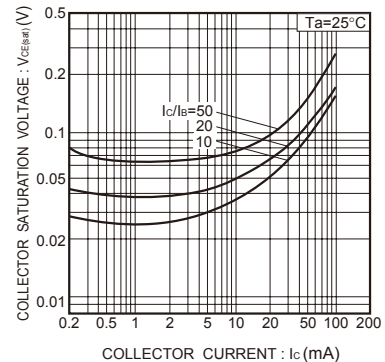


Fig.6 Collector-emitter saturation voltage vs. collector current

Transistors

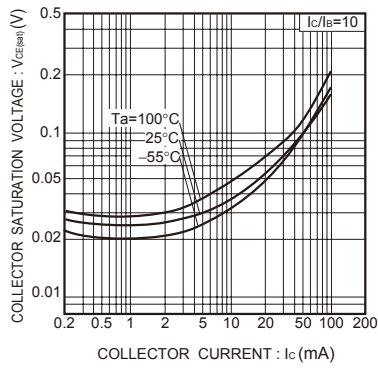


Fig.7 Collector-emitter saturation voltage vs. collector current (I)

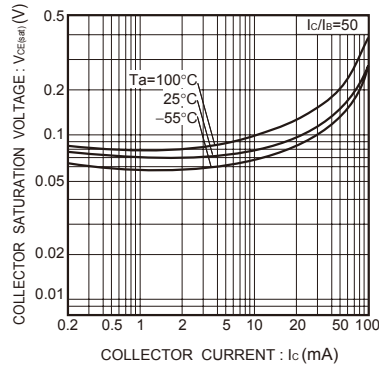


Fig.8 Collector-emitter saturation voltage vs. collector current (II)

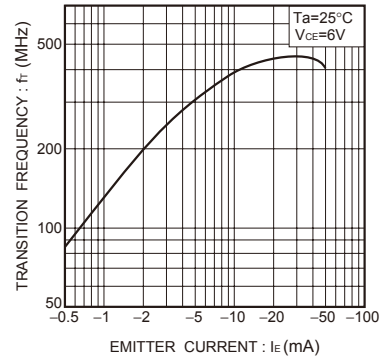


Fig.9 Gain bandwidth product vs. emitter current

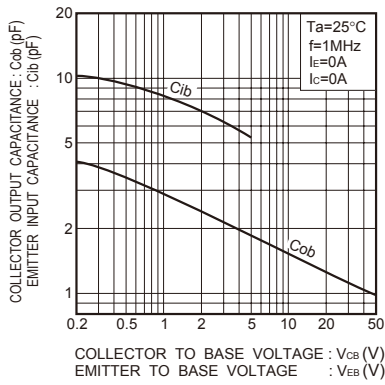


Fig.10 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

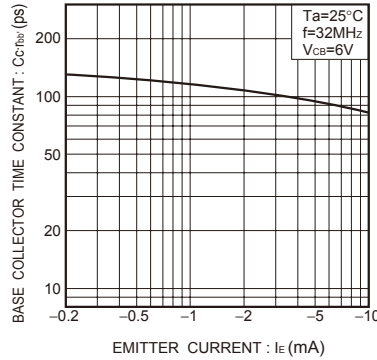


Fig.11 Base-collector time constant vs. emitter current

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